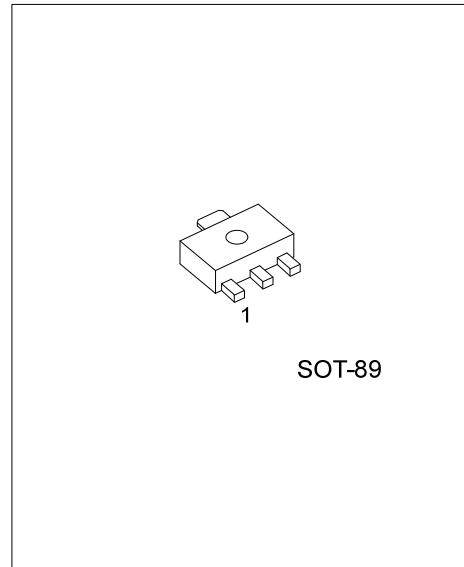




# 2SC3357

## NPN SILICON TRANSISTOR

NPN EPITAXIAL SILICON RF TRANSISTOR  
HIGH-FREQUENCY LOW-NOISE AMPLIFICATION POWER MINI MOLD



### DESCRIPTION

The UTC **2SC3357** is an NPN silicon epitaxial transistor designed for low noise amplifier at VHF, UHF and CATV band. It has large dynamic range and good current characteristic.

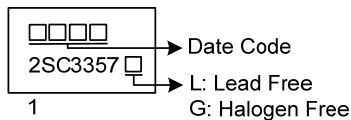
### ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2SC3357L-xx-AB3-R	2SC3357G-xx-AB3-R	SOT-89	B	C	E	Tape Reel

Note: Pin Assignment: B: Base C: Collector E: Emitter

<p>2SC3357G-xx-AB3-R</p> <ul style="list-style-type: none"> <li>(1)Packing Type</li> <li>(2)Package Type</li> <li>(3)Rank</li> <li>(4)Green Package</li> </ul>	<ul style="list-style-type: none"> <li>(1) R: Tape Reel</li> <li>(2) AB3: SOT-89</li> <li>(3) xx: refer to Classification of <math>h_{FE}</math></li> <li>(4) G: Halogen Free and Lead Free, L: Lead Free</li> </ul>
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### MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector to Base Voltage	$V_{CBO}$	20	V
Collector to Emitter Voltage	$V_{CEO}$	12	V
Emitter to Base Voltage	$V_{EBO}$	3	V
Collector Current	$I_C$	100	mA
Collector Dissipation	$P_C$	1.2	W
Junction Temperature	$T_J$	+150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-40 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.  
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ( $T_J=25^\circ\text{C}$ , unless otherwise specified)

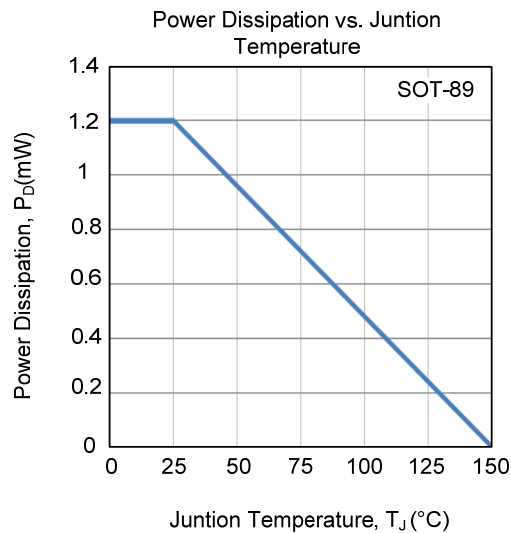
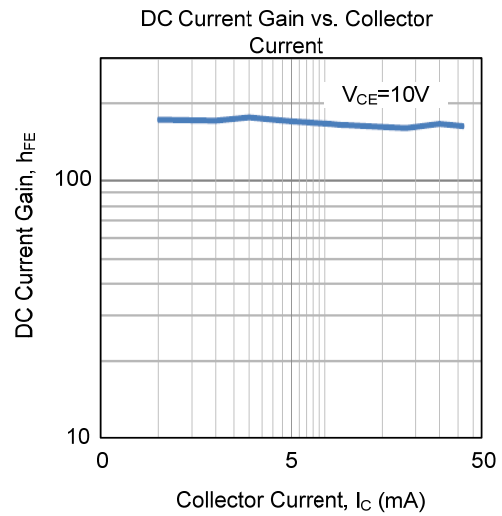
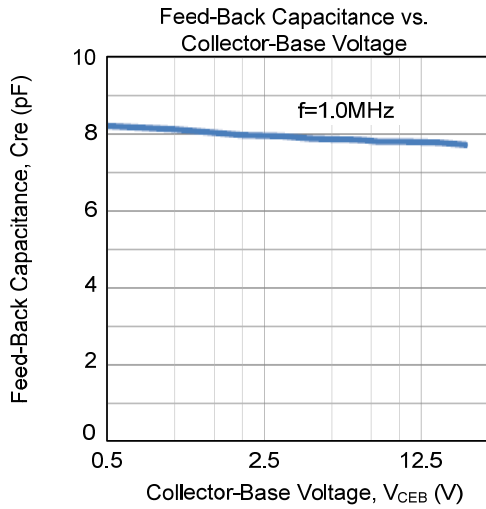
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CE}=10\text{V}, I_E=0$			1	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{CE}=1\text{V}, I_C=0$			1	$\mu\text{A}$
DC Current Gain	$h_{FE}$	$V_{CE}=10\text{V}, I_C=20\text{mA}$	50		300	
Transition Frequency	$f_T$	$V_{CE}=10\text{V}, I_C=20\text{mA}$		6.5		GHz
Feedback Capacitance	$C_{re}$	$V_{CE}=10\text{V}, I_E=0, f=1\text{MHz}$			10	pF

Note: Pulsed:  $P_W \leq 350\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

■ CLASSIFICATION OF  $h_{FE}$

RANK	RH	RF	RE
RANGE	50 ~ 100	80 ~ 160	125 ~ 250

## ■ TYPICAL CHARACTERISTICS



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.